## NSN 5961-00-278-9632

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Inclosure N	
Metal	
Overall Ler	-
	170 inches and 0.210 inches
Terminal L	-
0.500 inche	
Overall Dia	
	209 inches and 0.230 inches
	onfiguration:
Field effect	
	nternally-electrically Connected To Case:
Gate	
Mounting N	Method:
Terminal	
	ircle Diameter:
0.100 inche	
Features P	
-	y sealed case
	uctor Material:
Silicon	
-	ting In Volts Per Characteristic:
40.0 drain t	to gate voltage and 40.0 drain to source voltage and 40.0 gate to source voltage
Current Ra	ting Per Characteristic:
10.00 millia	mperes forward gate current
Power Rati	ng Per Characteristic:
	otal power dissipation
	ype And Quantity:
3 uninsulate	ed wire lead
Shelf Life:	
N/a	
Unit Of Mea	asure:
Demilitariz	ation:
No	
Fiig:	
A110a0	